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| APPLICATION NO. | FILING DATE | FIRST NAMED INVENTOR | ATTORNEY DOCKET NO. | CONFIRMATION NO. | |
|--------------------------------|-------------------------------|----------------------|-------------------------|------------------|--|
| 10/643,690 | 08/19/2003 | Yoshiyuki Kurokawa | 0553-0323.01 | 5081 | |
| 75 | 90 06/14/2004 | | EXAMINER | | |
| Edward D. Manzo | | | CLARK, JASMINE JHIHAN B | | |
| Cook, Alex, Mo Cummings & M | | | ART UNIT PAPER NUMBER | | |
| | 200 West Adams St., Ste. 2850 | | | | |
| Chicago, IL 6 | 0606 | | DATE MAILED: 06/14/2004 | | |

Please find below and/or attached an Office communication concerning this application or proceeding.

| | | | <i>A</i> Y | | | |
|---|--|--|------------|--|--|--|
| | Application No. | Applicant(s) | 7 | | | |
| | 10/643,690 | KUROKAWA ET AL. | | | | |
| Office Action Summary | Examiner | Art Unit | | | | |
| | Jasmine J Clark | 2815 | | | | |
| Th MAILING DATE of this communication Period for Reply | n app ars on the cover she to | vith the correspond nce addres | is | | | |
| A SHORTENED STATUTORY PERIOD FOR F THE MAILING DATE OF THIS COMMUNICAT - Extensions of time may be available under the provisions of 37 C after SIX (6) MONTHS from the mailing date of this communicati - If the period for reply specified above is less than thirty (30) days - If NO period for reply is specified above, the maximum statutory - Failure to reply within the set or extended period for reply will, by Any reply received by the Office later than three months after the earned patent term adjustment. See 37 CFR 1.704(b). | ION. FR 1.136(a). In no event, however, may a con. The construction is a reply within the statutory minimum of the period will apply and will expire SIX (6) MC at tatute, cause the application to become a construction. | a reply be timely filed hirty (30) days will be considered timely. ONTHS from the mailing date of this commu ABANDONED (35 U.S.C. § 133). | inication. | | | |
| Status | | | | | | |
| 1) Responsive to communication(s) filed on | | | | | | |
| , <u> </u> | This action is non-final. | | | | | |
| 3) Since this application is in condition for a | | | | | | |
| Disposition of Claims | | | | | | |
| 4) ⊠ Claim(s) <u>1-28</u> is/are pending in the application 4a) Of the above claim(s) is/are with 5) □ Claim(s) is/are allowed. 6) ⊠ Claim(s) <u>1-28</u> is/are rejected. 7) □ Claim(s) is/are objected to. 8) □ Claim(s) are subject to restriction is | thdrawn from consideration. | | | | | |
| Application Papers | | | | | | |
| 9)☐ The specification is objected to by the Exa | | | | | | |
| 10) ☐ The drawing(s) filed on is/are: a) ☐ accepted or b) ☐ objected to by the Examiner. | | | | | | |
| Applicant may not request that any objection | | | 40471) | | | |
| Replacement drawing sheet(s) including the control of the control | | | | | | |
| Priority under 35 U.S.C. § 119 | | | | | | |
| 12) Acknowledgment is made of a claim for for a) All b) Some * c) None of: 1. Certified copies of the priority docu 2. Certified copies of the priority docu 3. Copies of the certified copies of the application from the International E * See the attached detailed Office action for | uments have been received. uments have been received in e priority documents have bee Bureau (PCT Rule 17.2(a)). | Application No en received in this National Sta | ge | | | |
| Attachment(s) | 4) □ Int:- | (Summany /DTO 442) | | | | |
| Notice of References Cited (PTO-892) Notice of Draftsperson's Patent Drawing Review (PTO-9-3) Information Disclosure Statement(s) (PTO-1449 or PTO-Paper No(s)/Mail Date <u>08/19/03</u>. | 48) Paper N | v Summary (PTO-413) o(s)/Mail Date f Informal Patent Application (PTO-152 | 2) | | | |

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DETAILED ACTION

Claim Rejections - 35 USC § 112

1. Claims 1-28 are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

In claim 1, for example, the recitation "means for intercepting charge injection...; means for carrying out charge injection...; means for stopping charge injection..." is indefinite, and it is unclear exactly how the structure of these elements should be constructed or established. Please also see claims 7, 13, and 21.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35
 U.S.C. 102 that form the basis for the rejections under this section made in this
 Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 1-2, 4, 7-8, and 10 are rejected under 35 U.S.C. 102(b) as being anticipated by Tempel et al. (US 5,883,832), Applicants' submitted prior art.

Insofar as the claims are understood, they are clearly met by this reference. See, for example Fig. 2 of the reference where a plurality memory transistors comprise: an active layer 1 comprising a source region 3, a drain region 2 and a channel forming region 9; a first insulating film 6 formed on the active layer 1; a

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floating gate 4 formed on the first insulating film 6; a second insulating film 8 formed on the floating gate 4; and a control gate 7 formed on the second insulating film 8, a first region and a second region included in the channel forming region 9; means for intercepting charge injection from the first region to the floating gate ((a) see a thicker of the first insulating film between the floating gate and the channel and drain regions); means for carrying out charge injection from the first region to the floating gate ((b)see a thinner area of the first insulating film between the floating gate and the drain region 2); and means for stopping charge injection from the second region to the floating gate. (see (b)),

Concerning claim 2, wherein a thickness of the first insulating film formed on the first region is thicker than a thickness of the first insulating film formed on the second region (see (a) and (b) above), and see Fig. 2.

Concerning claim 4, wherein the memory transistor stores multi-value information, please see column 3, lines 18+).

Concerning claim 7, please see Fig. 3 for a plurality of memory transistors.

Concerning claims 8 and 10, please claims 2 and 4.

Claim Rejections - 35 USC § 103

- 3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

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This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

Claims 13-14, and 21-22 as best understood are rejected under 35 U.S.C. 103(a) as being unpatentable over the reference as applied to claims 1-2, 4, 7-8 and 10 above, and further in view of Ra (US 6,087,223), Applicants' submitted prior art.

As per the above discussion, the applied reference teach having a floating gate on the first insulating film, but fail to teach having a second floating gate as claimed. Ra teach having a plurality of floating gates formed on an insulating film. Hence, it would have been obvious to one having ordinary skill in the art at the time the invention was made to have more than one floating gate, as is notoriously known.

Concerning claims 14 and 22, please the above discussion under claim 2.

Telephone Inquiry Contacts

5. The references of interest are cited:

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Sato et al. (US 4,630), Kawamura et al. (US 406,524), Morii (US 5,847,411), Forbes (US 6,384,448 B1), and Kurokawa et al. (US 6,621,130 B2) teach a semiconductor device which relates to a memory transistor including a floating gate and control gate.

Telephone Inquiry Contacts

6. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Jasmine J Clark whose telephone number is (571) 272-1726. The examiner can normally be reached on Flex.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Tom Thomas can be reached on (571) 272-1664. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Jjbc/06/12/04

JASMINE CLARK PRIMARY EXAMINER